TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX541F,TC74LCX541FT,TC74LCX541FK

Low-Voltage Octal Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX541 is a high-performance CMOS octal bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

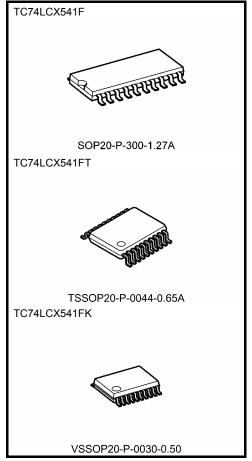
The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

The TC74LCX541 is a non-inverting 3-state buffer having two active-low output enables. When either $\overline{OE}1$ or $\overline{OE}2$ are high, the terminal outputs are in the high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

Features

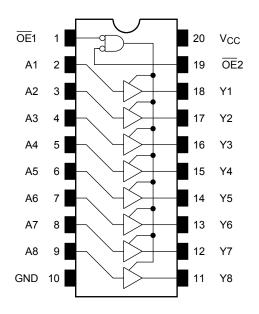
- Low-voltage operation: VCC = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 6.5 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: -500 mA
- Available in JEITA SOP, TSSOP and VSSOP (US)
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 541 type



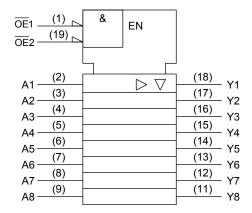
Weight:

SOP20-P-300-1.27A : 0.22 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

	Inputs					
OE1	OE2	DE2 An Outputs				
Н	Х	Х	Z			
Х	Н	Х	Z			
L	L	Н	Н			
L	L	L	L			

X: Don't care

Z: High impedance



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5 to 7.0	
DC input voltage	V _{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
		(Note 3)	
Input diode current	l _{IK}	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	P_{D}	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	–65 to 150 °	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc

Operating Ranges (Note 1)

Characteristics	Symbol	ol Rating			
Power supply voltage	V _{CC}	2.0 to 3.6			
rower suppry voltage	vCC	1.5 to 3.6 (Note 2)	V		
Input voltage	V _{IN}	0 to 5.5	٧		
Output voltage	V	0 to 5.5 (Note 3)	V		
Output voltage	V _{OUT}	0 to V _{CC} (Note 4)	V		
Output current	la/la.	±24 (Note 5)	mA		
Output current	I _{OH} /I _{OL}	±12 (Note 6)	IIIA		
Operating temperature	T _{opr}	-40 to 85	°C		
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V		

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

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Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Cumbal	Symbol Test Condition			Min	May	Unit		
Character	Sucs	Symbol	rest Condition		V _{CC} (V)	IVIIII	Max	Unit		
Input voltage	H-level	V _{IH}		_	2.7 to 3.6	2.0	_	V		
input voltage	L-level	V _{IL}		_	2.7 to 3.6	_	8.0	v		
				$I_{OH} = -100 \mu A$	2.7 to 3.6	to 3.6 VCC —				
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_			
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_			
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V		
			V VV	I _{OL} = 100 μA	2.7 to 3.6	_	0.2			
		V		I _{OL} = 12 mA	2.7	_	0.4			
	L-level	V _{OL}	VOL VII	$V_{IN} = V_{IH} \text{ or } V_{IL}$	AIM — AIH OI AIL	I _{OL} = 16 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55			
Input leakage currer	t	I _{IN}	V _{IN} = 0 to 5.5 V	•	2.7 to 3.6	_	±5.0	μА		
3-state output off-sta	ite current	loz	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OLIT} = 0 \text{ to } 5.5 \text{ V}$		2.7 to 3.6	_	±5.0	μА		
Power off leakage co	urrent	l _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μА		
			. V _{IN} = V _{CC} or GND		V _{IN} = V _{CC} or GND		_	10.0		
Quiescent supply cu	rrent	ICC	V _{IN} /V _{OUT} = 3.6 to 5.5 V		2.7 to 3.6	_	±10.0	μА		
Increase in I _{CC} per i	nput	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6	_	500			

AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Decree with a delection	t _{pLH}	Figure 4 Figure 0	2.7	_	7.5	
Propagation delay time	t _{pHL}	Figure 1, Figure 2	3.3 ± 0.3	1.5	6.5	ns
Cutaut analys time	t _{pZL}	Figure 1, Figure 3	2.7	_	9.5	ns
Output enable time	t _{pZH}	Figure 1, Figure 3	3.3 ± 0.3	1.5	8.5	
Output disable time	t _{pLZ}	Figure 1, Figure 3	2.7		8.5	ns
Output disable time	t _{pHZ}	rigure 1, rigure 3	3.3 ± 0.3	1.5	7.5	110
Output to output skew	t _{osLH}	(Note)	2.7	1	1	ns
Carpar to output snew	t _{osHL}	(Note)	3.3 ± 0.3		1.0	110

Note: Parameter guaranteed by design.

 $(t_{\text{OSLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, \, t_{\text{OSHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω)

Characteristics		Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic	V _{OL}	V _{OLP}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V
Quiet output minimum dynamic	V _{OL}	V _{OLV}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V



Capacitive Characteristics (Ta = 25°C)

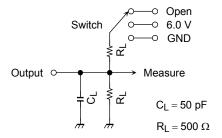
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_	3.3	7	pF
Output capacitance	C _{OUT}	_	3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note) 3.3	40	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

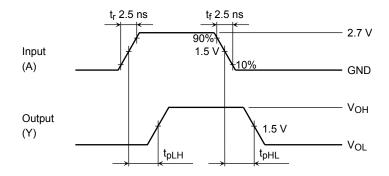


Figure 2 t_{pLH}, t_{pHL}

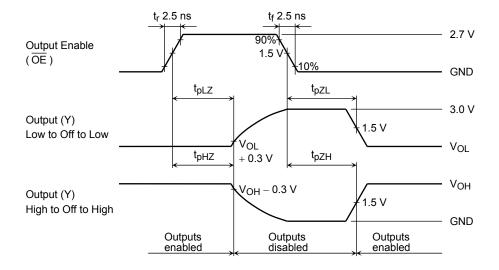
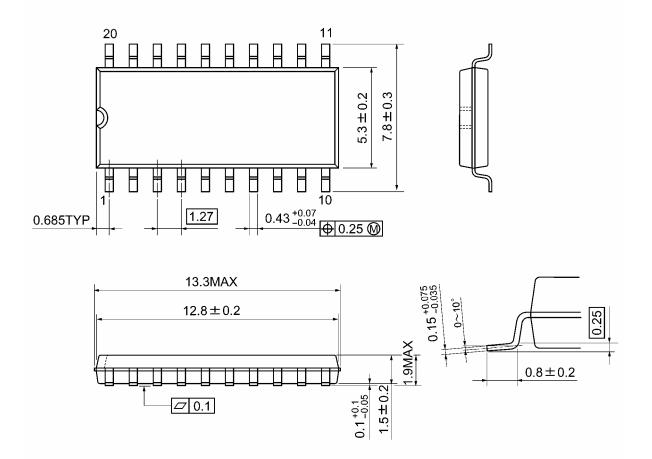


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

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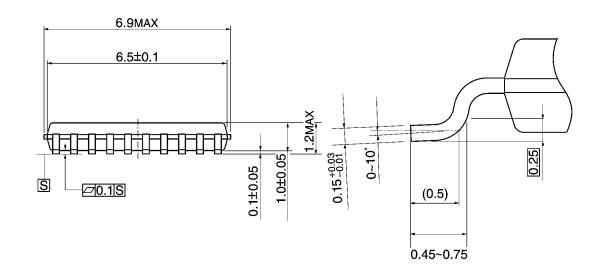
Package Dimensions

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

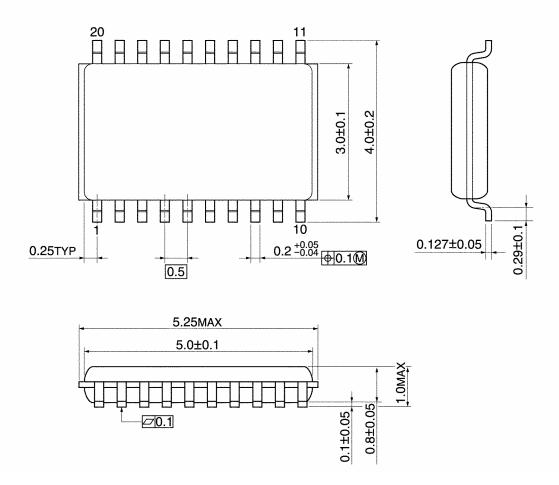
Package Dimensions



Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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